

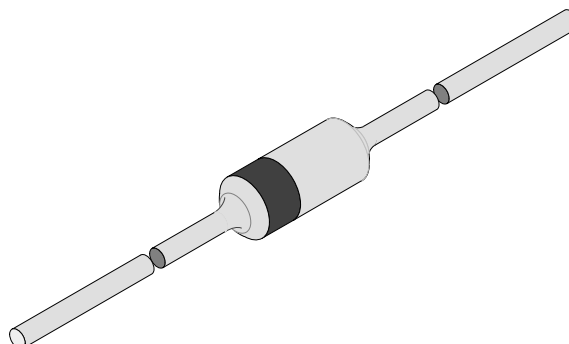
Small Signal Schottky Barrier Diodes

Features

- Integrated protection ring against static discharge
- Low capacitance
- Low leakage current
- Low forward voltage drop

Applications

HF–Detector
Protection circuit
Diode for low currents with a low supply voltage
Small battery charger
Power supplies
DC / DC converter for notebooks



94 9367

Order Instruction

Type	Type Differentiation	Ordering Code	Remarks
SD101A	$V_R=60\text{ V}$, $V_F@I_F1\text{mA}$ max. 0.41 V	SD101A–TAP	Ammopack
		SD101A–TR	Tape and Reel
SD101B	$V_R=50\text{ V}$, $V_F@I_F1\text{mA}$ max. 0.4 V	SD101B–TAP	Ammopack
		SD101B–TR	Tape and Reel
SD101C	$V_R=40\text{ V}$, $V_F@I_F1\text{mA}$ max. 0.39 V	SD101C–TAP	Ammopack
		SD101C–TR	Tape and Reel

Absolute Maximum Ratings

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Reverse voltage		SD101A	V_R	60	V
		SD101B	V_R	50	V
		SD101C	V_R	40	V
Peak forward surge current	$t_p=10\mu\text{s}$		I_{FSM}	2	A
Repetitive peak forward current			I_{FRM}	150	mA
Forward current			I_F	30	mA
Junction temperature			T_j	125	$^\circ\text{C}$
Storage temperature range			T_{stg}	–65...+150	$^\circ\text{C}$

Maximum Thermal Resistance

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	on PC board 50 mmx50 mmx1.6 mm	R_{thJA}	320	K/W

Electrical Characteristics

 $T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage	$I_R = 10\mu\text{A}$	SD101A	$V_{(BR)R}$	60			V
		SD101B	$V_{(BR)R}$	50			V
		SD101C	$V_{(BR)R}$	40			V
Leakage current	$V_R = 50\text{ V}$	SD101A	I_R			200	nA
	$V_R = 40\text{ V}$	SD101B	I_R			200	nA
	$V_R = 30\text{ V}$	SD101C	I_R			200	nA
Forward voltage drop	$I_F = 1\text{mA}$	SD101A	V_F			0.41	V
		SD101B	V_F			0.4	V
		SD101C	V_F			0.39	V
	$I_F = 15\text{mA}$	SD101A	V_F			1	V
		SD101B	V_F			0.95	V
		SD101C	V_F			0.9	V
Diode capacitance	$V_R = 0\text{ V}, f = 1\text{MHz}$	SD101A	C_D			2.0	pF
		SD101B	C_D			2.1	pF
		SD101C	C_D			2.2	pF

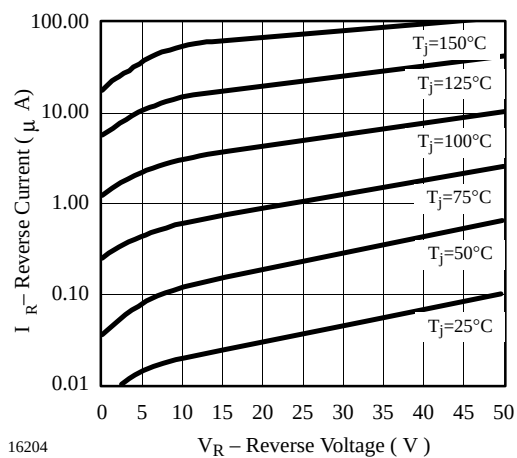
Characteristics ($T_j = 25^\circ\text{C}$ unless otherwise specified)

Figure 1. Reverse Current vs. Reverse Voltage

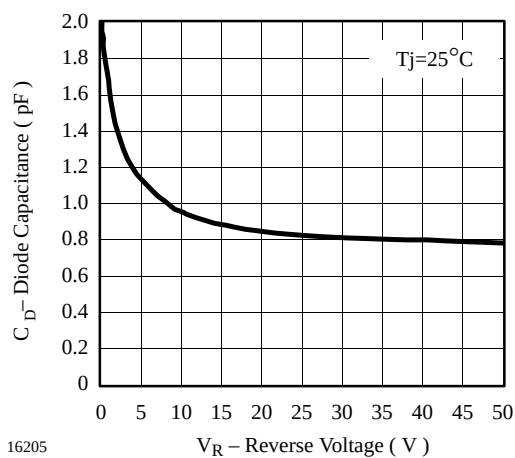


Figure 2. Diode Capacitance vs. Reverse Voltage

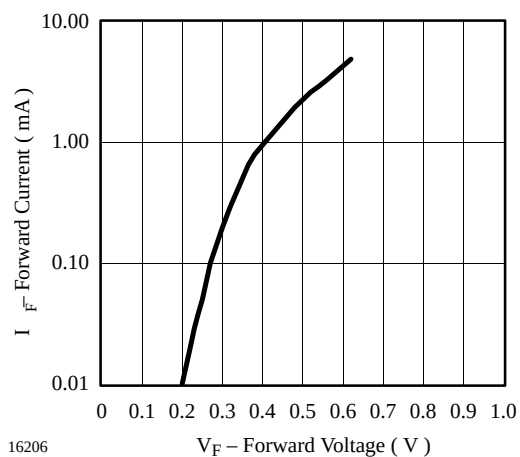


Figure 3. Forward Current vs. Forward Voltage

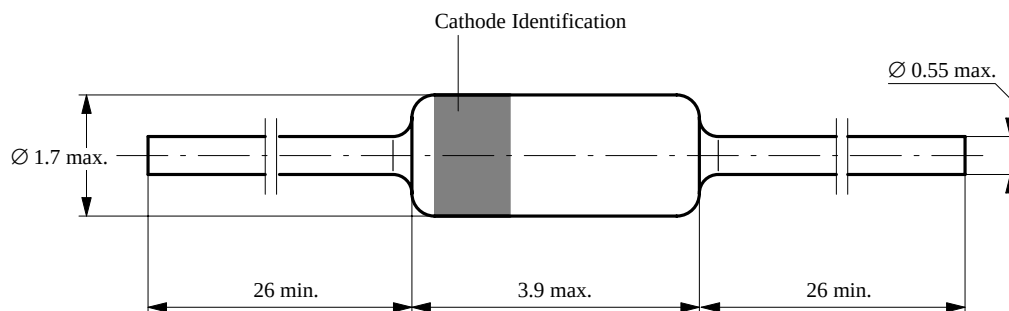
Dimensions in mm



technical drawings
according to DIN
specifications

94 9366

Standard Glass Case
54 A 2 DIN 41880
JEDEC DO 35
Weight max. 0.3g



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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